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## BU326A

## HIGH VOLTAGE NPN SILICON POWER TRANSISTOR

SGS-THOMSON PREFERRED SALESTYPE

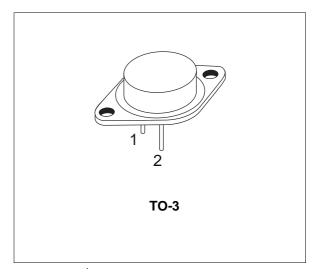
- NPN TRANSISTOR
- FAST SWITCHING SPEED

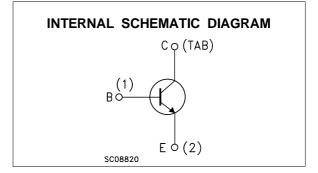
#### **APPLICATIONS:**

- POWER SUPPLIES
- LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT

#### DESCRIPTION

The BU326A is a silicon multiepitaxial mesa NPN transistor in Jedec TO-3 metal case particularly intended for switch-mode CTV supply system.





#### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
VCES	Collector-Emitter Voltage (V <sub>BE</sub> = 0)	900	V	
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)	400	V	
$V_{EBO}$	Emitter-Base Voltage $(I_C = 0)$	10	V	
Ι <sub>C</sub>	Collector Current	6	А	
I <sub>CM</sub>	Collector Peak Current	8	А	
IB	Base Current	3	А	
Ptot	Total Power Dissipation at $T_{case} \le 25 \ ^{\circ}C$	75	W	
T <sub>stg</sub>	Storage Temperature	-65 to 200	°C	
Tj	Max. Operating Junction Temperature	200	°C	

#### THERMAL DATA

R <sub>thj-case</sub> Thermal Resistance Junction-case	Max	2.33	°C/W
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### **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25 \ ^{o}C$ unless otherwise specified)

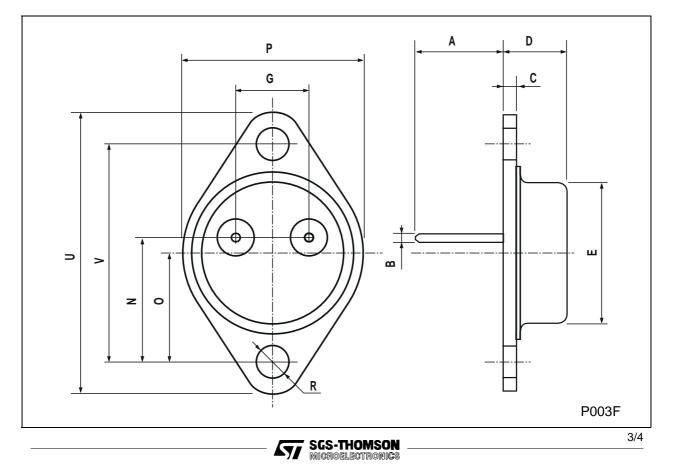
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
ICES	Collector Cut-off Current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 900 V V <sub>CE</sub> = 900 V	T <sub>c</sub> = 125 <sup>o</sup> C			1 2	mA mA
I <sub>EBO</sub>	Emitter Cut-off Current $(I_{C} = 0)$	V <sub>EB</sub> = 10 V				10	mA
$V_{CEO(sus)}*$	Collector-Emitter Sustaining Voltage(I <sub>B</sub> = 0)	I <sub>C</sub> = 100 mA		400			V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2.5 A I <sub>C</sub> = 4 A	I <sub>B</sub> = 0.5 A I <sub>B</sub> = 1.25 A			1.5 3	V V
V <sub>BE(sat)</sub> *	Base-Emitter Saturation Voltage	I <sub>C</sub> = 2.5 A I <sub>C</sub> = 4 A	I <sub>B</sub> = 0.5 A I <sub>B</sub> = 1.25 A			1.4 1.6	V
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 1 A	$V_{CE} = 5 V$		25		
t <sub>on</sub>	Turn-on Time	I <sub>C</sub> = 2.5 A V <sub>CC</sub> = 250 V	I <sub>B1</sub> = 0.5 A			0.5	μs
ts	Storage Time	I <sub>C</sub> = 2.5 A I <sub>B2</sub> = -1A A	I <sub>B1</sub> = 0.5 A V <sub>CC</sub> = 250 V			3.5	μs
t <sub>f</sub>	Fall Time		I <sub>B1</sub> = 0.5 A V <sub>CC</sub> = 250 V			0.5	μs

\* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %



TO-3 MECHANICAL DATA

DIM.		mm			inch	
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	11.00		13.10	0.433		0.516
В	0.97		1.15	0.038		0.045
С	1.50		1.65	0.059		0.065
D	8.32		8.92	0.327		0.351
E	19.00		20.00	0.748		0.787
G	10.70		11.10	0.421		0.437
N	16.50		17.20	0.649		0.677
Р	25.00		26.00	0.984		1.023
R	4.00		4.09	0.157		0.161
U	38.50		39.30	1.515		1.547
V	30.00		30.30	1.187		1.193



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